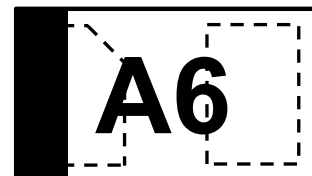


1N4148DB

Features

- High voltage
- Small package
- Small capacitance

DFN1x0.6-2L



1.Cathode  2.Anode

Marking Code: A6

Absolute Maximum Ratings at $T_A = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Value	Unit
Maximum Repetitive Reverse Voltage	V_{RRM}	100	V
Reverse Voltage	V_R	75	V
Average Rectified Forward Current	$I_{F(AV)}$	200	mA
DC Forward Current	I_{FM}	600	mA
Repetitive Peak Forward Current	I_{FRM}	700	mA
Non-repetitive Peak Forward Surge Current	I_{FSM}	1	A
at $t = 1\text{ s}$		4	
at $t = 1\text{ }\mu\text{s}$			
Power Dissipation	P_D	250	mW
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^{\circ}\text{C}$

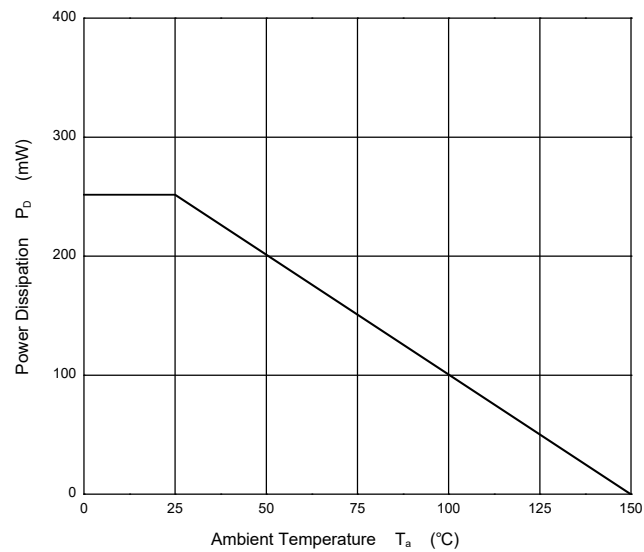
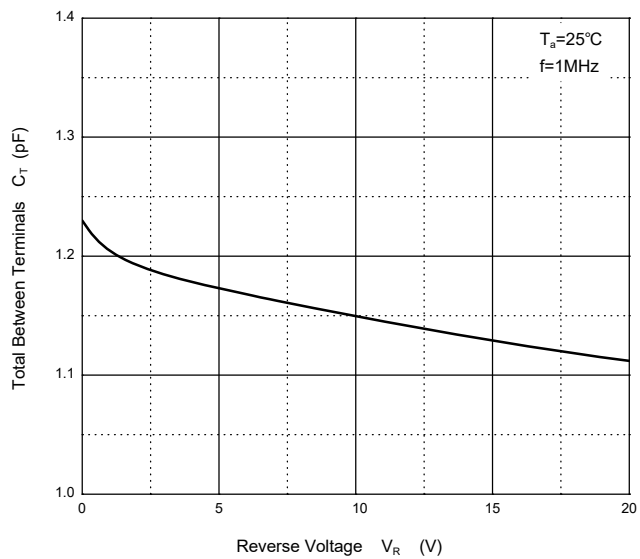
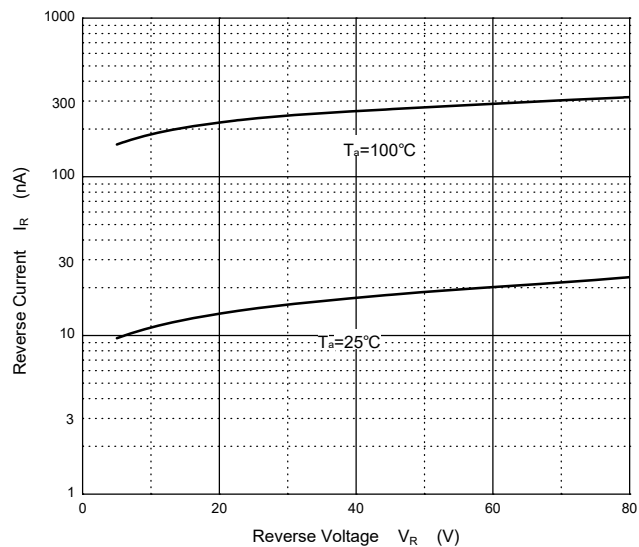
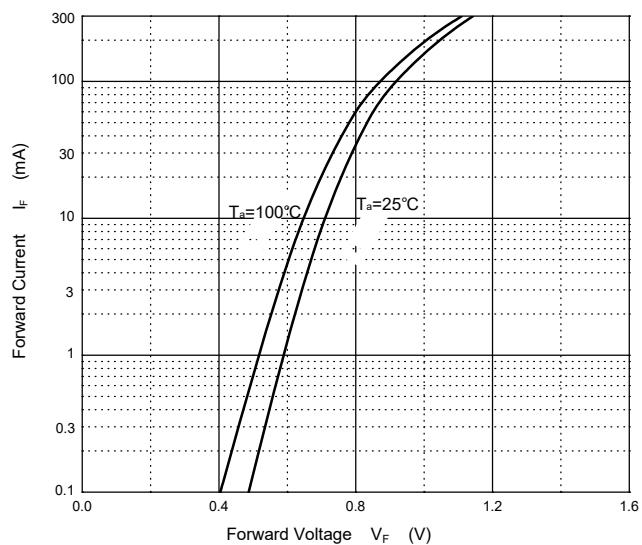
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Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 10\text{ mA}$	V_F	--	0.85	V
Reverse Breakdown Voltage at $I_R = 100\text{ }\mu\text{A}$ at $I_R = 5\text{ }\mu\text{A}$	$V_{(BR)R}$	100 75	-- --	V
Reverse Current at $V_R = 20\text{ V}$ at $V_R = 75\text{ V}$ at $V_R = 20\text{ V}$, at $T_A = 150\text{ }^{\circ}\text{C}$	I_R	-- -- --	25 1 50	nA μA μA
Typical Junction Capacitance at $V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_j	--	4	pF
Maximum Reverse Recovery Time at $I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_{RR} = 1\text{ mA}$, $R_L = 100\text{ }\Omega$	T_{rr}	--	4	nS

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Typical Characteristic Curves

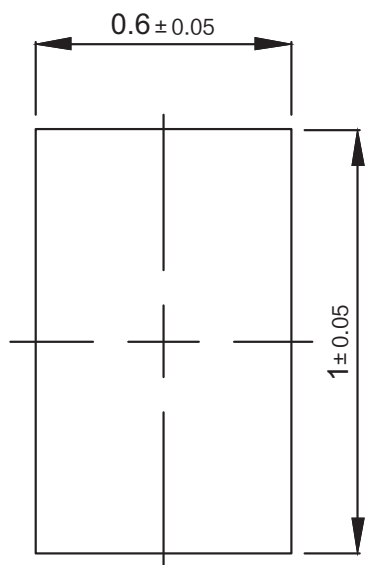


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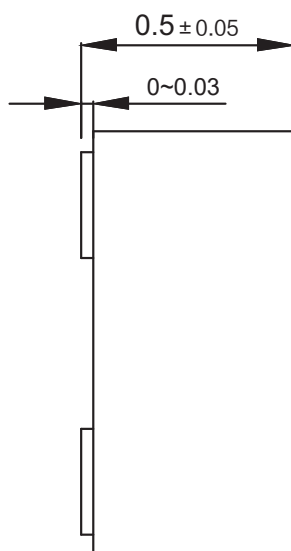
Package Outline

DFN1x0.6-2L-0011

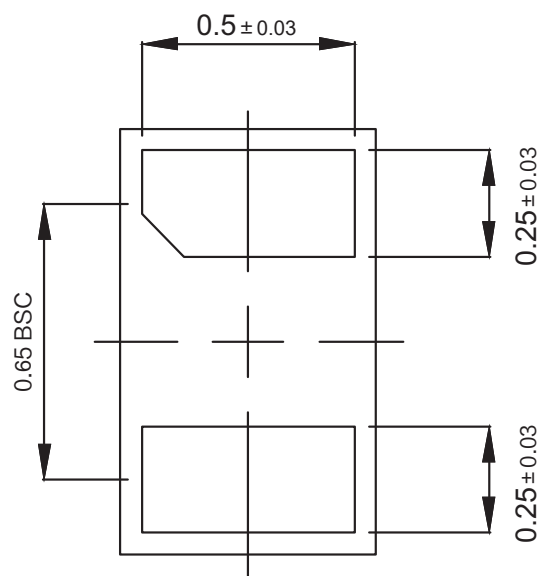
Dimensions in mm



TOP VIEW



SIDE VIEW



BOTTOM VIEW

Ordering Information

Device	Package	Shipping
1N4148DB	DFN1x0.6-2L	10,000PCS/Reel&7inches